

HA1630Q04/05/06 Series

Low Voltage Operation CMOS Quad Operational Amplifier

REJ03D0803-0100

Rev.1.00

Mar 10, 2006

Description

The HA1630Q04/05/06 are high slew rate single CMOS Operational Amplifiers realizing low voltage operation, low input offset voltage and low supply current. In addition to a low operating voltage from 1.8V, these device output can achieve full swing output voltage capability extending to either supply. Available in an ultra-small TSSOP-14 package that occupies only 1/4 the area of the SOP-14 package.

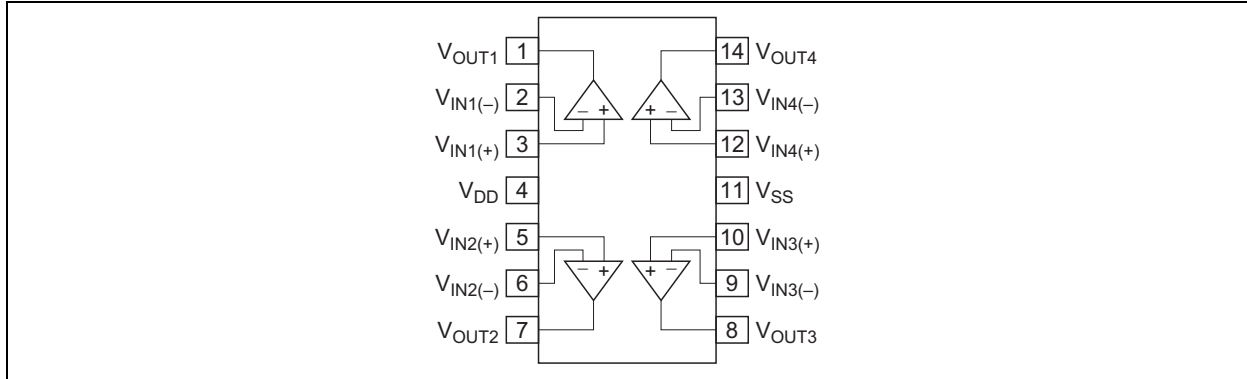
Features

- Low power and single supply operation $V_{DD} = 1.8$ to 5.5 V
- Low input offset voltage $V_{IO} = 4.0$ mV Max
- Low supply current (per channel)
 - $I_{DD} = 200$ μ A Typ (HA1630Q04)
 - $I_{DD} = 400$ μ A Typ (HA1630Q05)
 - $I_{DD} = 800$ μ A Typ (HA1630Q06)
- High slew rate
 - SR = 2 V/ μ s Typ (HA1630Q04)
 - SR = 4 V/ μ s Typ (HA1630Q05)
 - SR = 8 V/ μ s Typ (HA1630Q06)
- Maximum output voltage $V_{OH} = 2.9$ V Min (at $V_{DD} = 3.0$ V)
- Low input bias current $I_{IB} = 1$ pA Typ

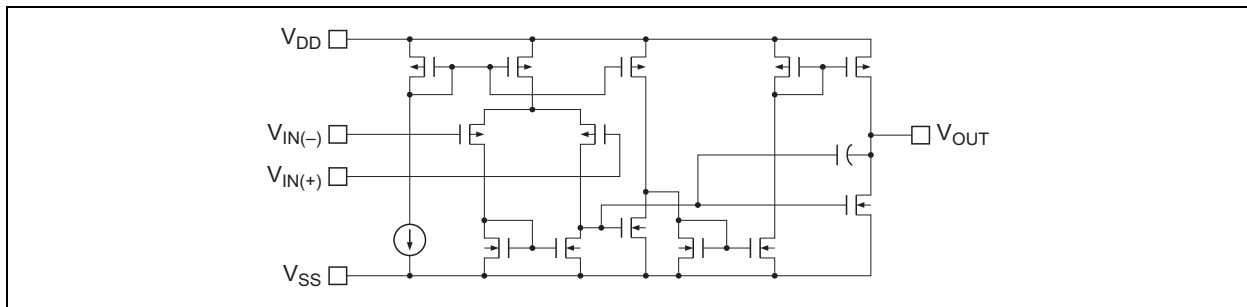
Ordering Information

Type No.	Package Name	Package Code
HA1630Q04T	TTP-14D	PTSP0014JA-B
HA1630Q05T	TTP-14D	PTSP0014JA-B
HA1630Q06T	TTP-14D	PTSP0014JA-B

Pin Arrangement



Equivalent Circuit (per one channel)



Absolute Maximum Ratings

(Ta = 25°C)

Items	Symbol	Ratings	Unit	Note
Supply voltage	V _{DD}	7	V	
Differential input voltage	V _{IN(diff)}	-V _{DD} to +V _{DD}	V	
Input voltage	V _{IN}	-0.3 to +V _{DD}	V	1
Power dissipation	P _T	400	mW	
Operating temp. Range	Topr	-40 to +85	°C	
Storage temp. Range	Tstg	-55 to +125	°C	

Note: 1. Do not apply Input Voltage exceeding V_{DD} or 7 V.

Electrical Characteristics

(V_{DD} = 3.0 V, Ta = 25°C)

Items	Symbol	Min	Typ	Max	Unit	Test Condition
Input offset voltage	V _{IO}	—	—	4.0	mV	V _{in} = 1.5 V
Input offset current	I _{IO}	—	(1.0)	—	pA	V _{in} = 1.5 V
Input bias current	I _{IB}	—	(1.0)	—	pA	V _{in} = 1.5 V
Output high voltage	V _{OH}	2.9	—	—	V	R _L = 100 kΩ
Output source current	I _{O SOURCE}	100	200	—	μA	V _{OH} = 2.5 V (HA1630Q04)
		200	400	—		V _{OH} = 2.5 V (HA1630Q05)
		400	800	—		V _{OH} = 2.5 V (HA1630Q06)
Output low voltage	V _{OL}	—	—	0.1	V	R _L = 100 kΩ
Output sink current	I _{O SINK}	—	(5.0)	—	mA	V _{OL} = 0.5 V (HA1630Q04)
		—	(6.0)	—		V _{OL} = 0.5 V (HA1630Q05)
		—	(6.5)	—		V _{OL} = 0.5 V (HA1630Q06)
Common mode input voltage range	V _{CM}	-0.05 to 2.1	—	—	V	(HA1630Q04, HA1630Q05)
		0 to 1.9	—	—		(HA1630Q06)
Slew rate	SR	—	(2.0)	—	V/μs	C _L = 20 pF (HA1630Q04)
		—	(4.0)	—		C _L = 20 pF (HA1630Q05)
		—	(8.0)	—		C _L = 20 pF (HA1630Q06)
Voltage gain	A _V	60	90	—	dB	
Gain bandwidth product	BW	—	(2100)	—	kHz	C _L = 20 pF (HA1630Q04)
		—	(3300)	—		C _L = 20 pF (HA1630Q05)
		—	(3600)	—		C _L = 20 pF (HA1630Q06)
Power supply rejection ratio	PSRR	50	70	—	dB	
Common mode rejection ratio	CMRR	50	70	—	dB	
Supply current	I _{DD}	—	0.8	1.6	mA	R _L = ∞ (HA1630Q04)
		—	1.6	3.2		R _L = ∞ (HA1630Q05)
		—	3.2	6.8		R _L = ∞ (HA1630Q06)

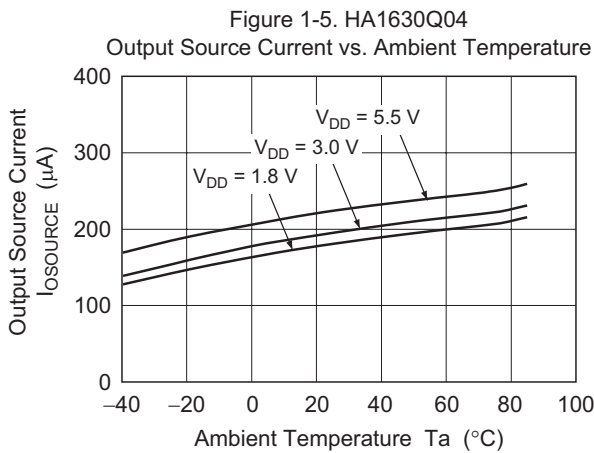
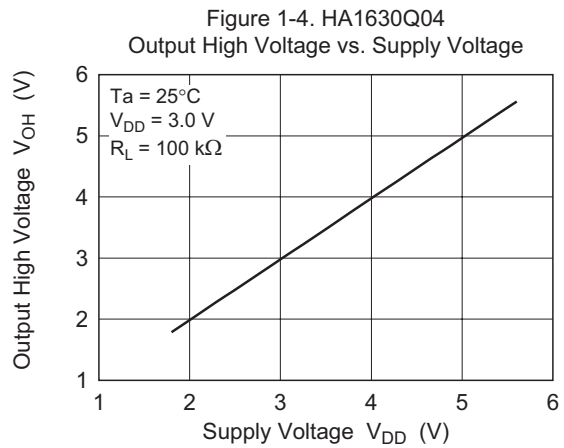
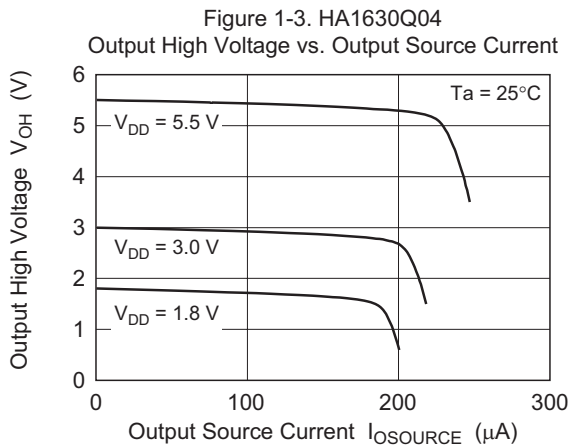
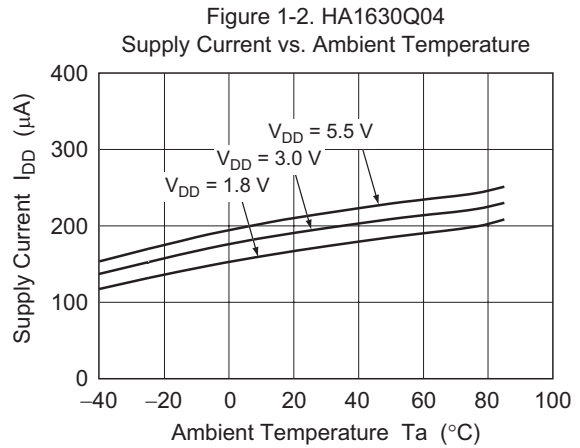
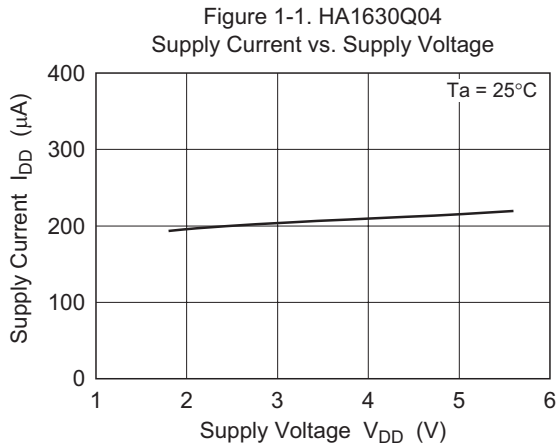
Notes: 1. In the case of continuous current flow, use a sink current of under 4 mA.

2. () : Design specification

Table of Graphs

Electrical Characteristics			HA1630Q04 Figure	HA1630Q05 Figure	HA1630Q06 Figure	Test Circuit
Supply current	I_{DD}	vs Supply voltage	1-1	2-1	3-1	2
		vs Ambient temperature	1-2	2-2	3-2	
Output high voltage	V_{OH}	vs Output source current	1-3	2-3	3-3	4
		vs Supply voltage	1-4	2-4	3-4	
Output source current	$I_{O\ SOURCE}$	vs Ambient temperature	1-5	2-5	3-5	6
Output low voltage	V_{OL}	vs Output sink current	1-6	2-6	3-6	5
Output sink current	$I_{O\ SINK}$	vs Ambient temperature	1-7	2-7	3-7	6
Input offset voltage	V_{IO}	Distribution	1-8	2-8	3-8	1
		vs Supply voltage	1-9	2-9	3-9	
		vs Ambient temperature	1-10	2-10	3-10	
Common mode input voltage range	V_{CM}	vs Ambient temperature	1-11	2-11	3-11	7
Power supply rejection ratio	PSRR	vs Frequency	1-12	2-12	3-12	1
Common mode rejection ratio	CMRR	vs Frequency	1-13	2-13	3-13	7
Voltage gain & phase angle	A_v	vs Frequency	1-14	2-14	3-14	10
Input bias current	I_{IB}	vs Ambient temperature	1-15	2-15	3-15	3
		vs Input voltage	1-16	2-16	3-16	
Slew Rate (rising)	SRr	vs Ambient temperature	1-17	2-17	3-17	9
Slew Rate (falling)	SRf	vs Ambient temperature	1-18	2-18	3-18	
Slew rate		Large signal transient response	1-19	2-19	3-19	
		Small signal transient response	1-20	2-20	3-20	
Total harmonic distortion + noise	(0 dB) (40 dB)	vs. Output voltage p-p	1-21	2-21	3-21	8
		vs. Output voltage p-p	1-22	2-22	3-22	
Maximum p-p output voltage		vs Frequency	1-23	2-23	3-23	
Voltage noise density		vs Frequency	1-24	2-24	3-24	

Main Characteristics (HA1630Q04)



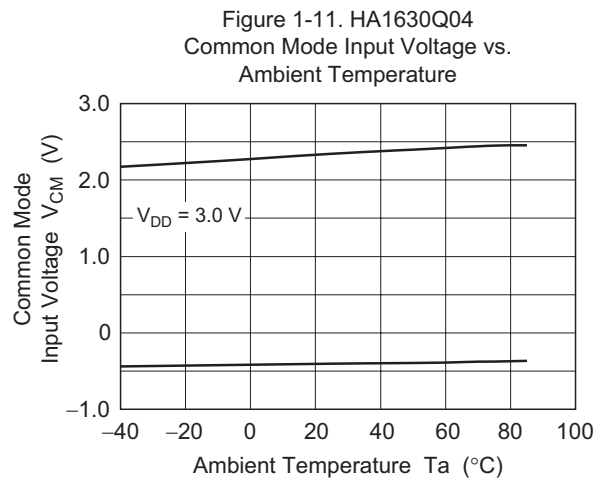
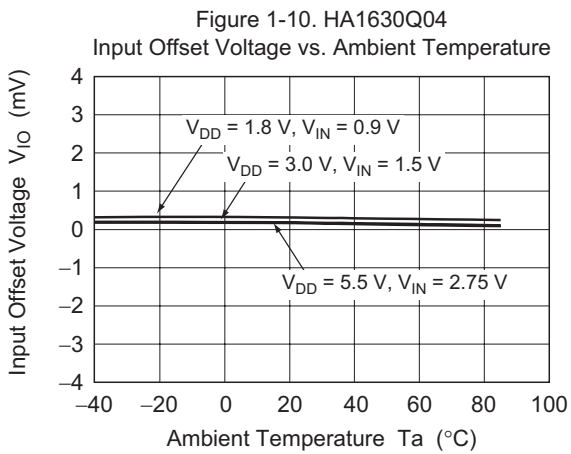
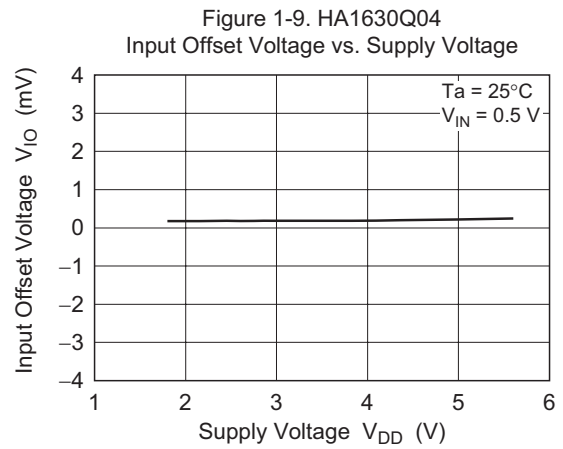
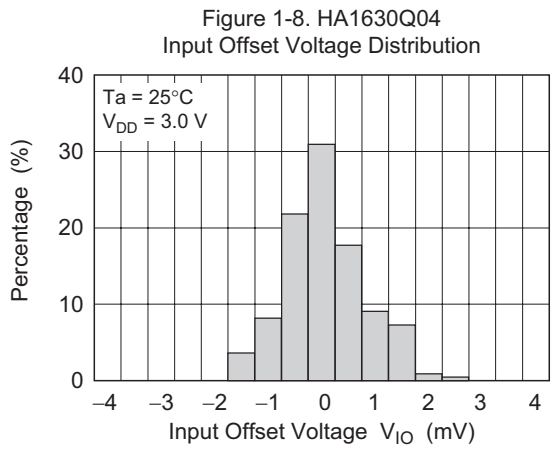
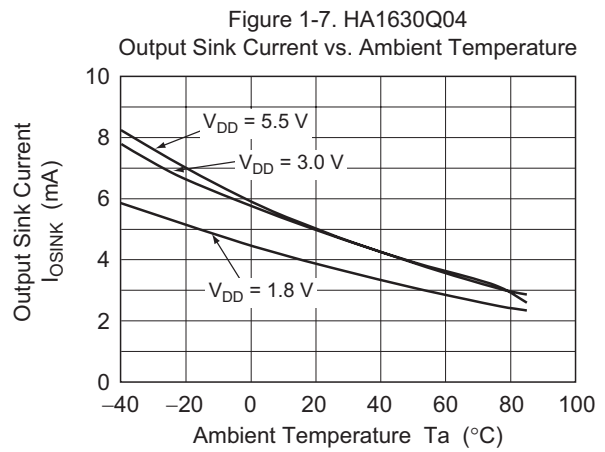
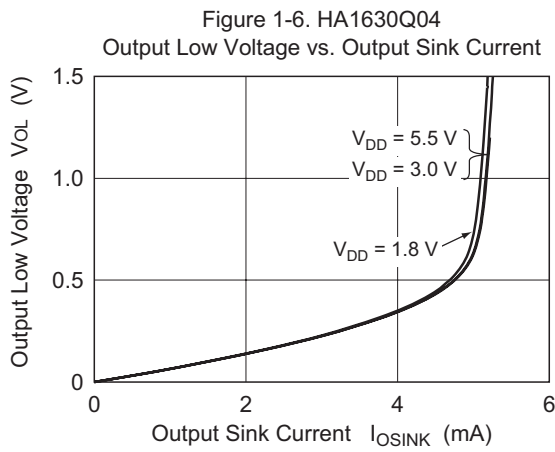


Figure 1-12. HA1630Q04
Power Supply Rejection Ratio vs. Frequency

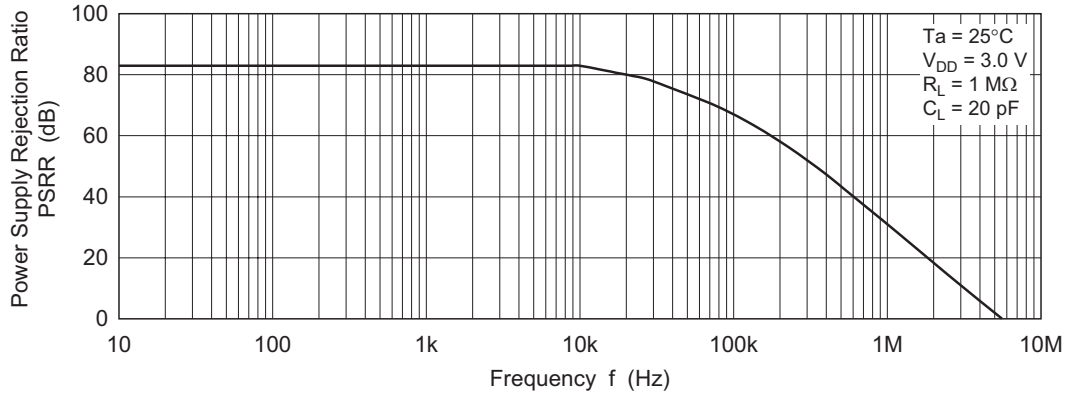


Figure 1-13. HA1630Q04
Common Mode Rejection Ratio vs. Frequency

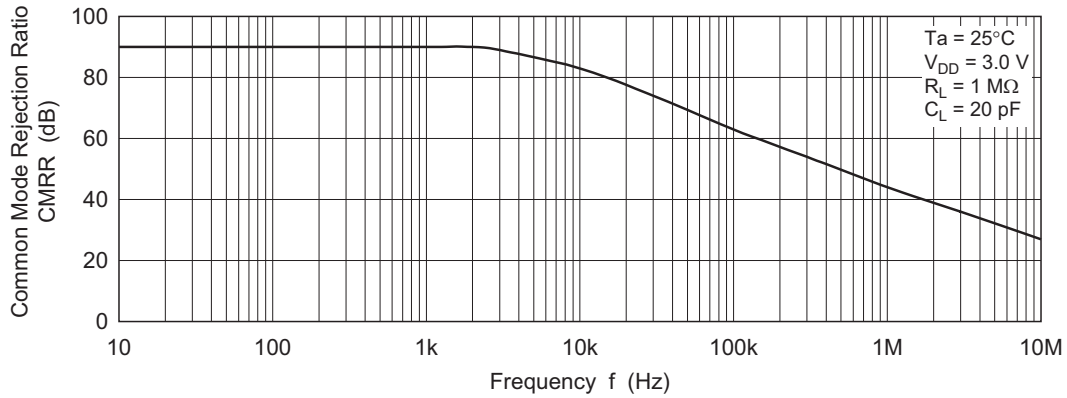


Figure 1-14. HA1630Q04
Open Loop Voltage Gain and Phase Angle vs. Frequency

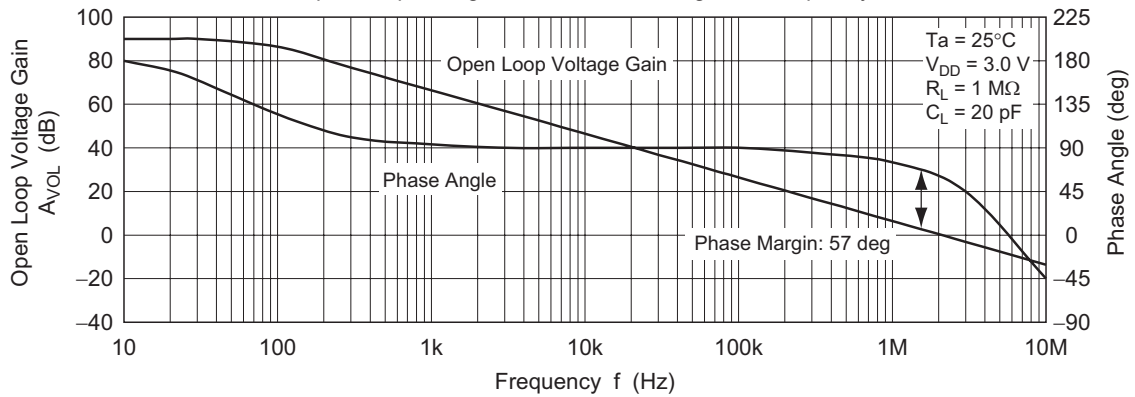


Figure 1-15. HA1630Q04
Input Bias Current vs. Ambient Temperature

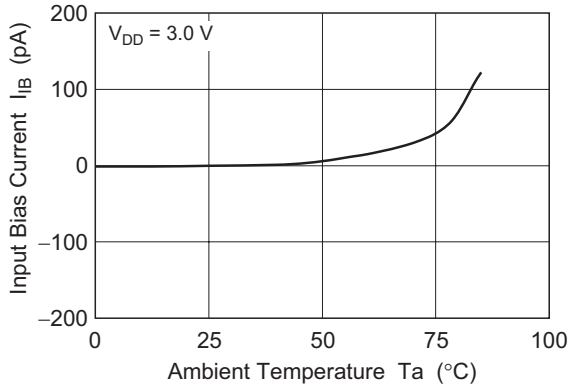


Figure 1-16. HA1630Q04
Input Bias Current vs. Input Voltage

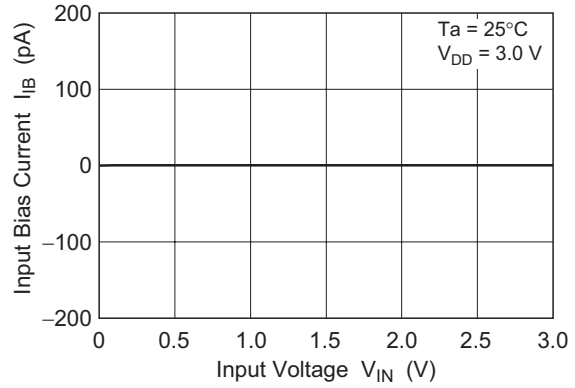


Figure 1-17. HA1630Q04
Slew Rate (rising) vs. Ambient Temperature

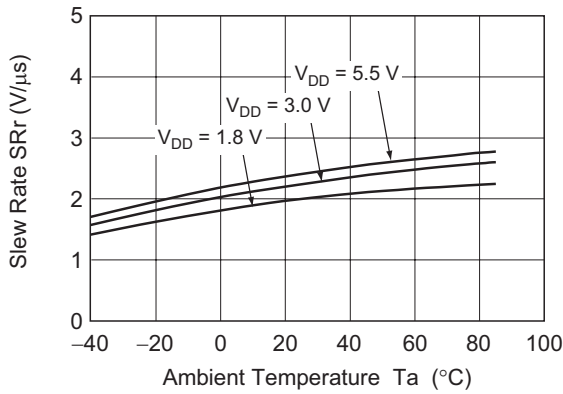


Figure 1-18. HA1630Q04
Slew Rate (falling) vs. Ambient Temperature

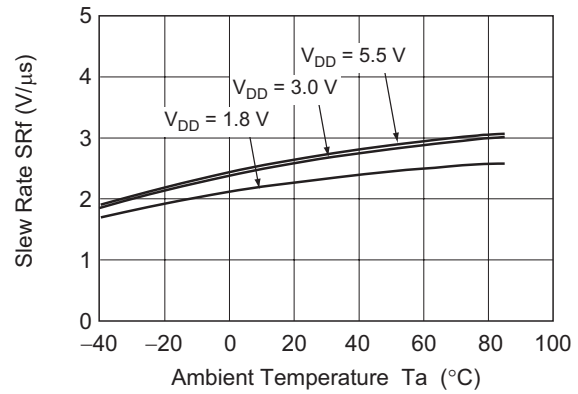


Figure 1-19. HA1630Q04
Large Signal Transient Response

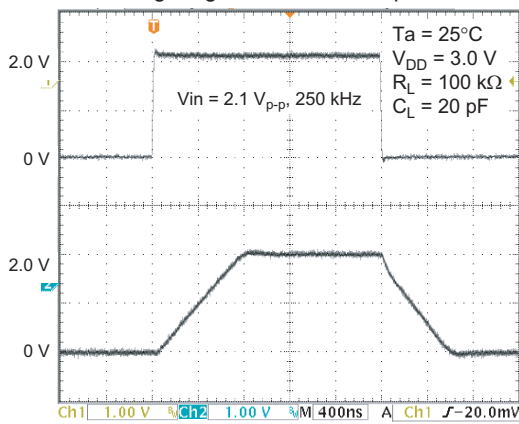


Figure 1-20. HA1630Q04
Small Signal Transient Response

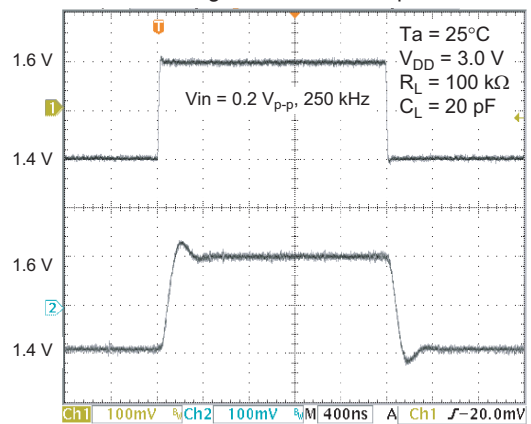


Figure 1-21. HA1630Q04
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

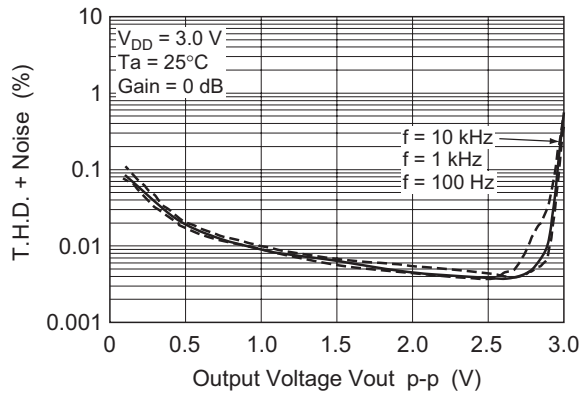


Figure 1-22. HA1630Q04
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

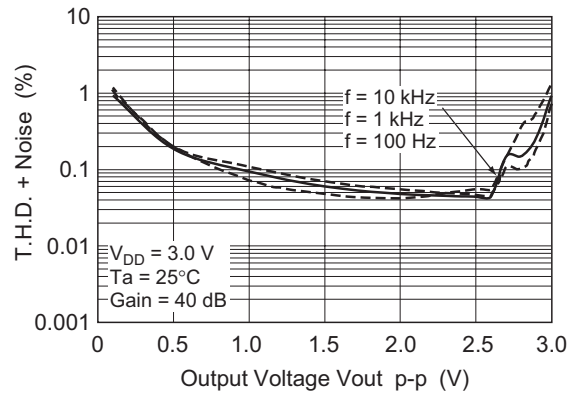


Figure 1-23. HA1630Q04
Voltage Output p-p vs. Frequency

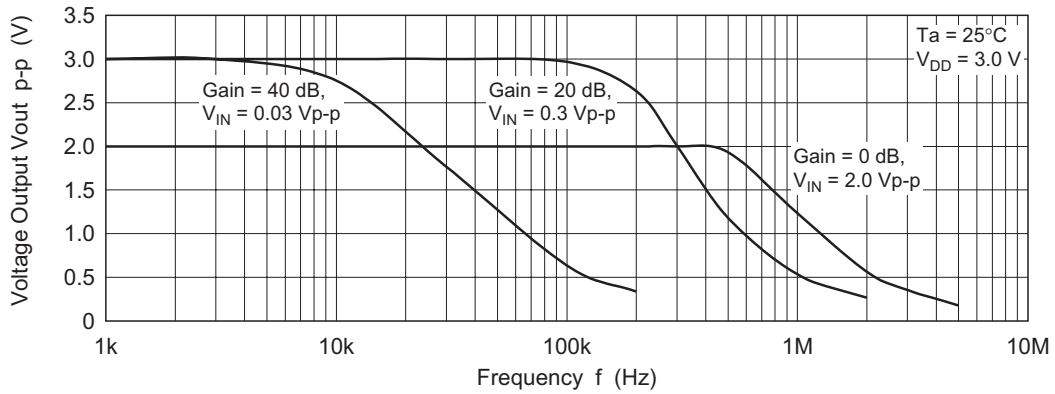
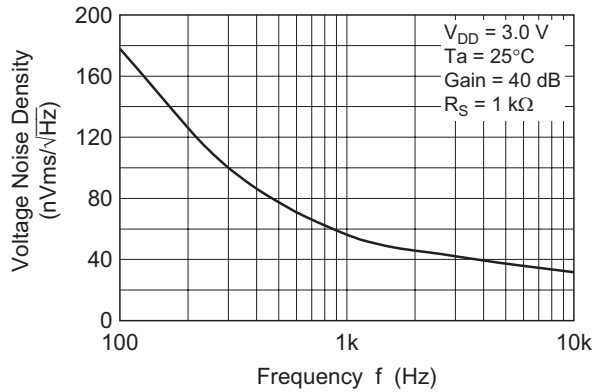
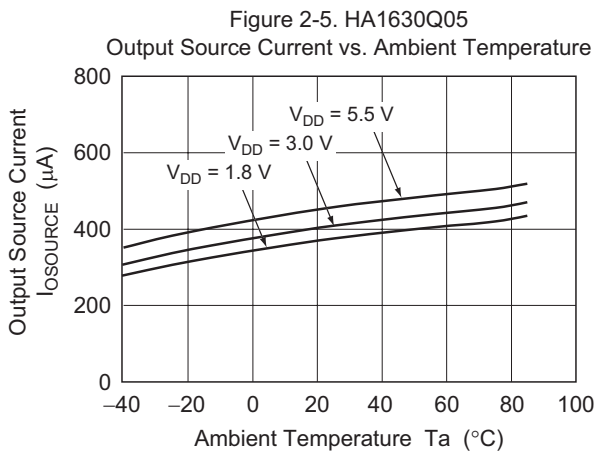
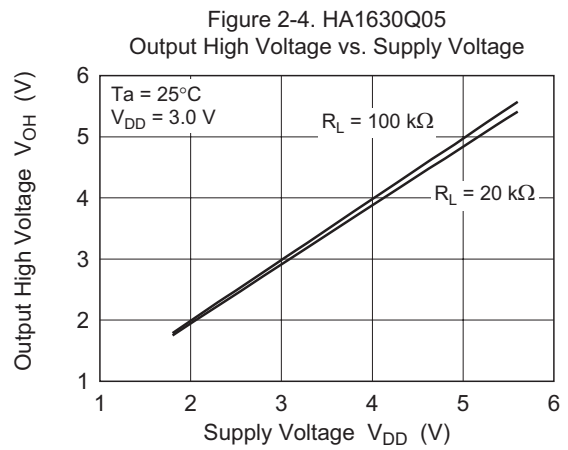
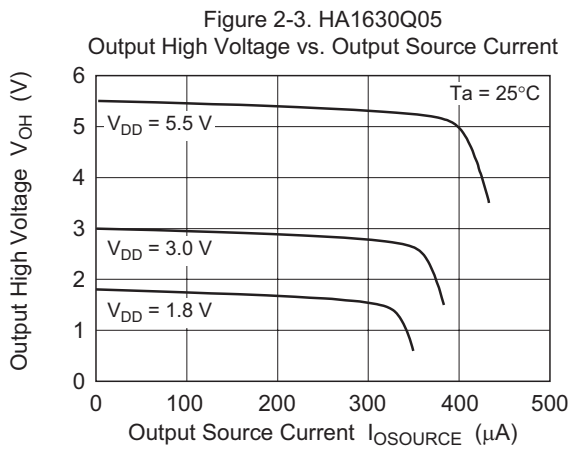
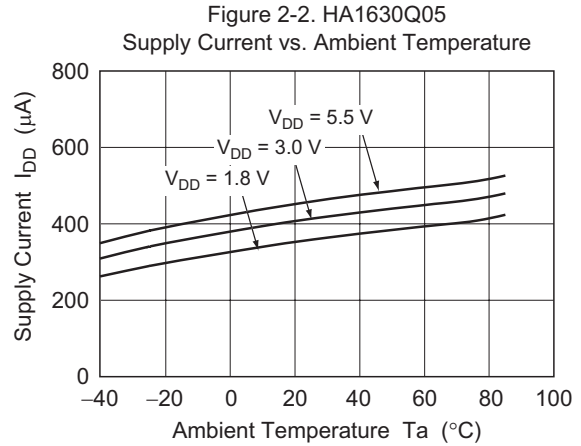
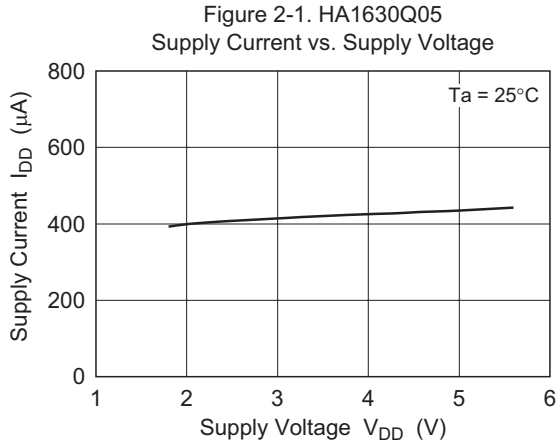


Figure 1-24. HA1630Q04
Voltage Noise Density vs. Frequency



Main Characteristics (HA1630Q05)



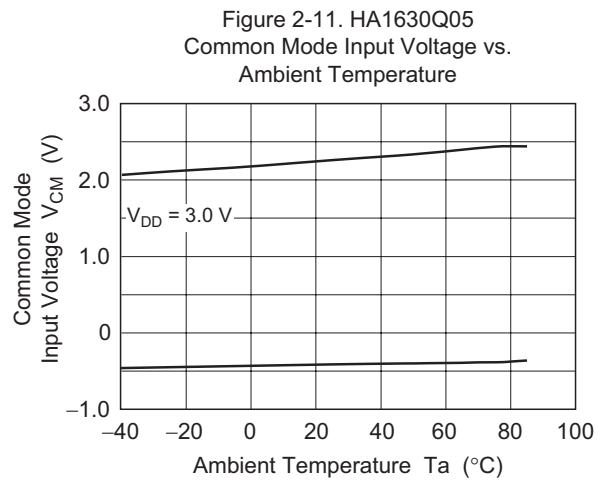
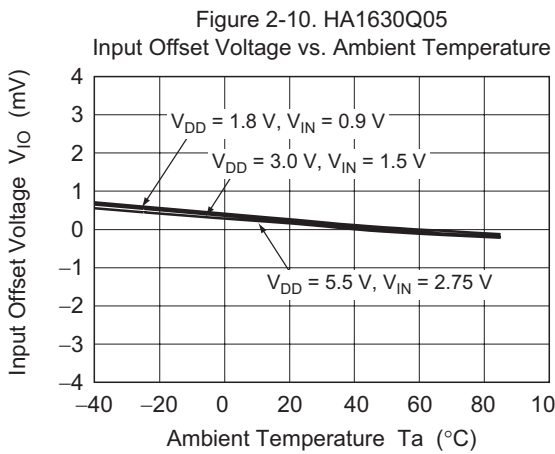
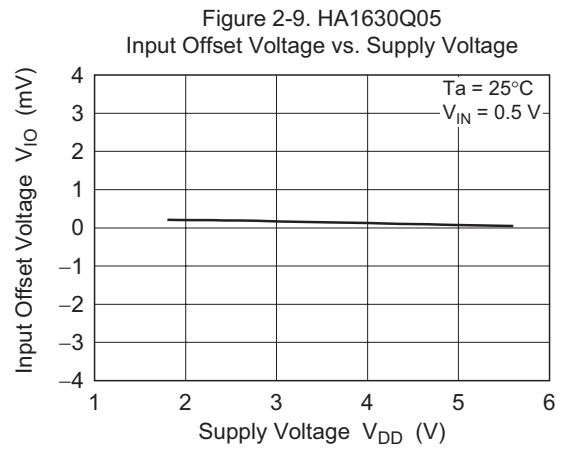
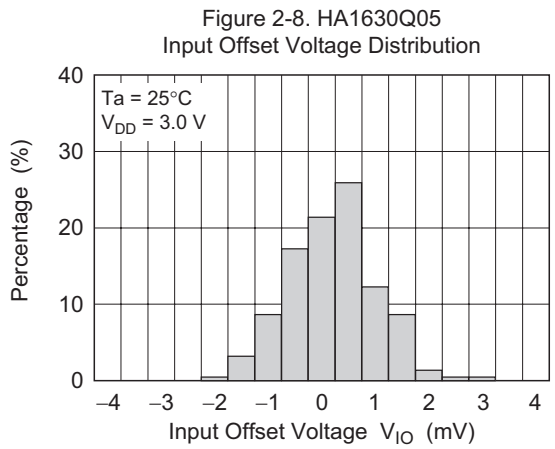
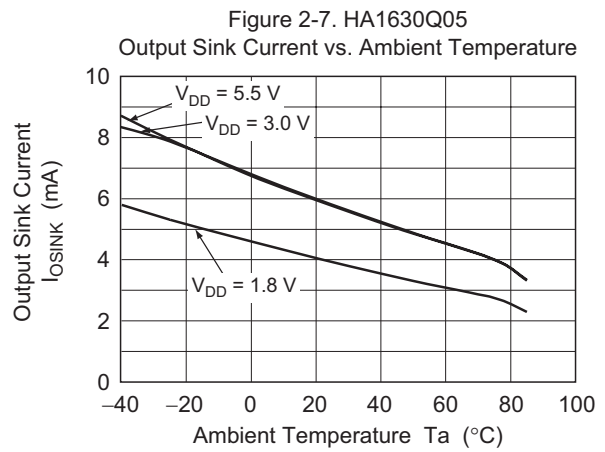
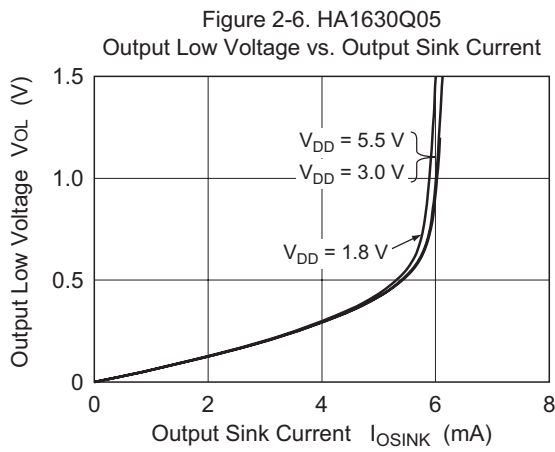


Figure 2-12. HA1630Q05
Power Supply Rejection Ratio vs. Frequency

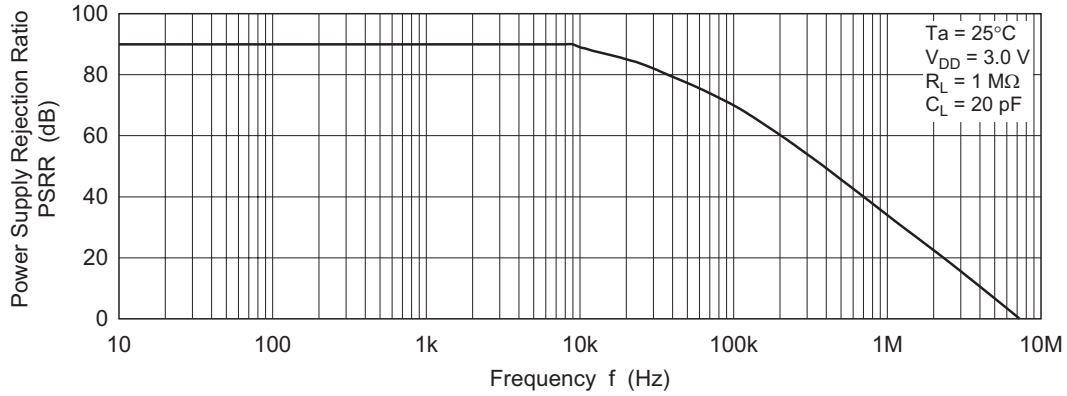


Figure 2-13. HA1630Q05
Common Mode Rejection Ratio vs. Frequency

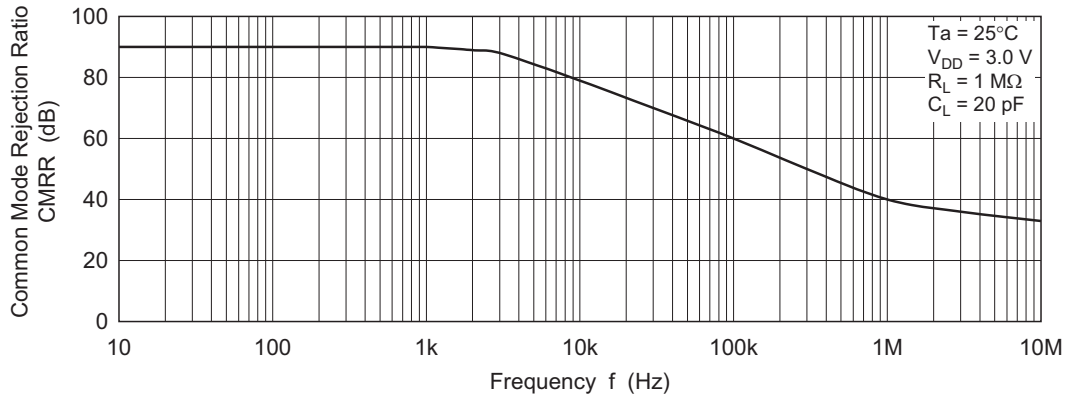


Figure 2-14. HA1630Q05
Open Loop Voltage Gain and Phase Angle vs. Frequency

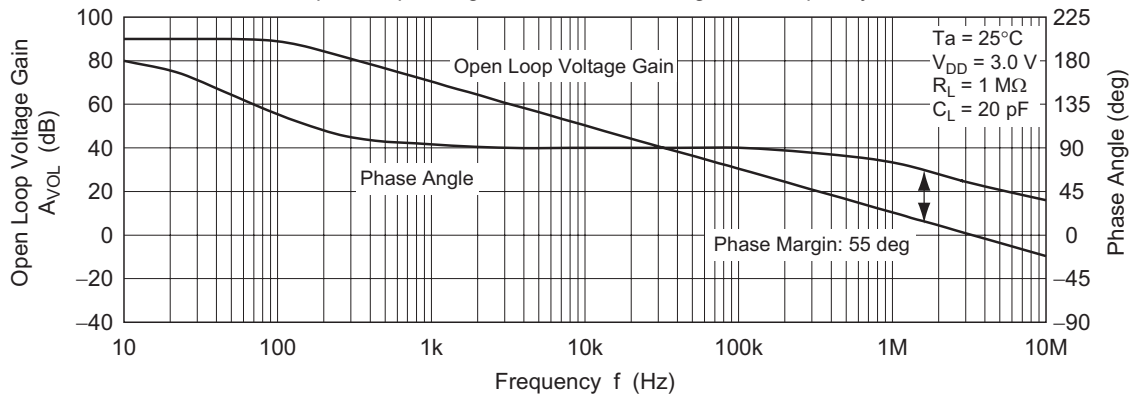


Figure 2-15. HA1630Q05
Input Bias Current vs. Ambient Temperature

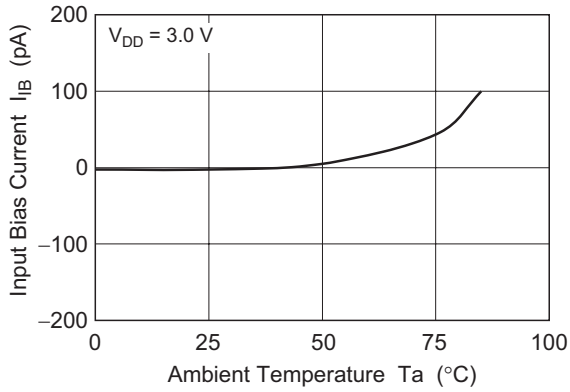


Figure 2-16. HA1630Q05
Input Bias Current vs. Input Voltage

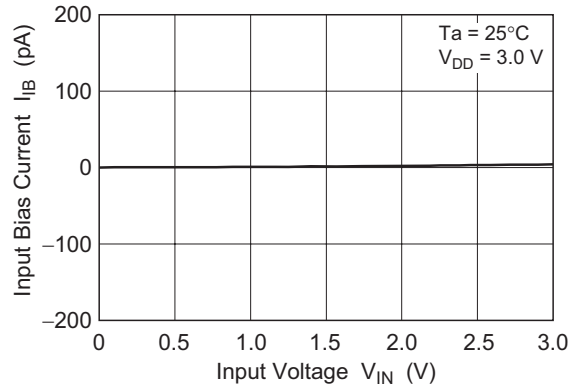


Figure 2-17. HA1630Q05
Slew Rate (rising) vs. Ambient Temperature

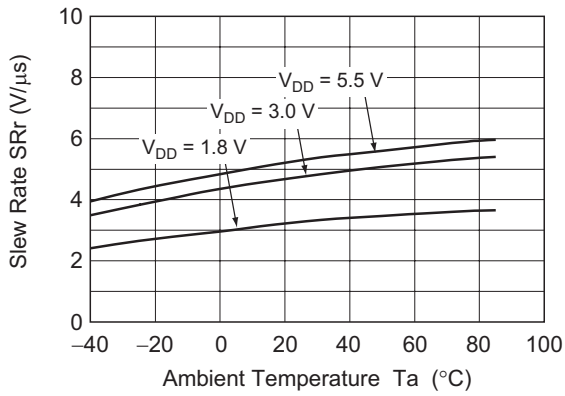


Figure 2-18. HA1630Q05
Slew Rate (falling) vs. Ambient Temperature

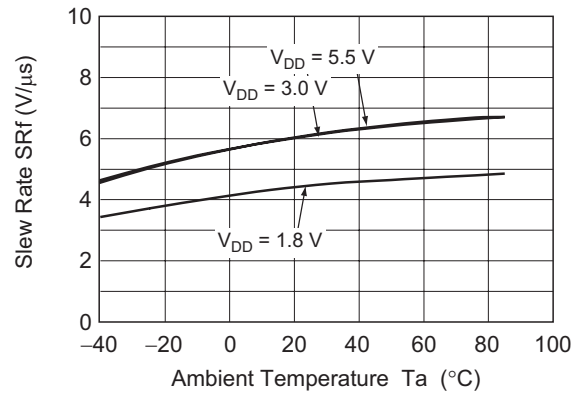


Figure 2-19. HA1630Q05
Large Signal Transient Response

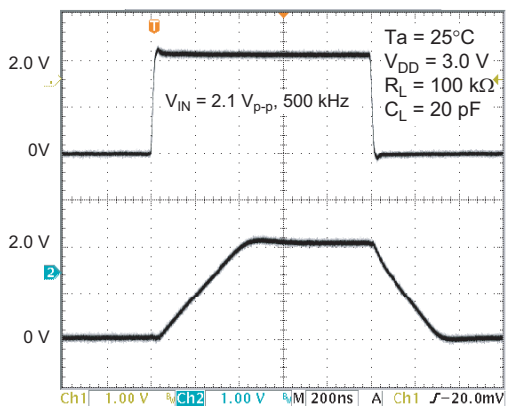


Figure 2-20. HA1630Q05
Small Signal Transient Response

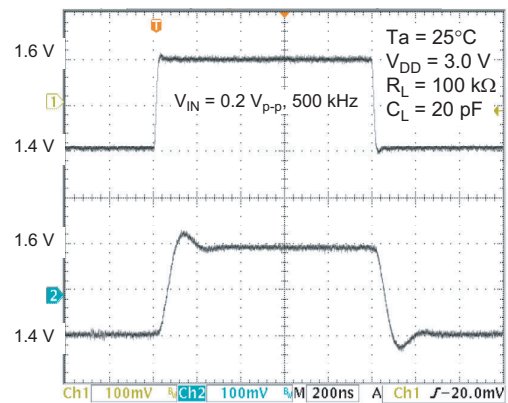


Figure 2-21. HA1630Q05
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

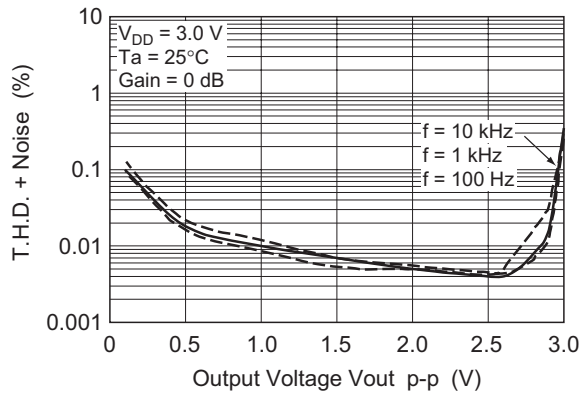


Figure 2-22. HA1630Q05
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

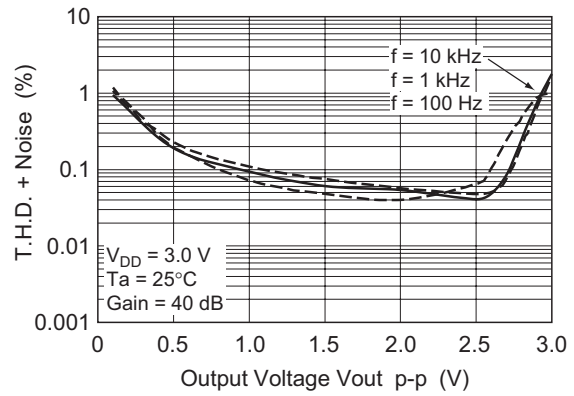


Figure 2-23. HA1630Q05
Voltage Output p-p vs. Frequency

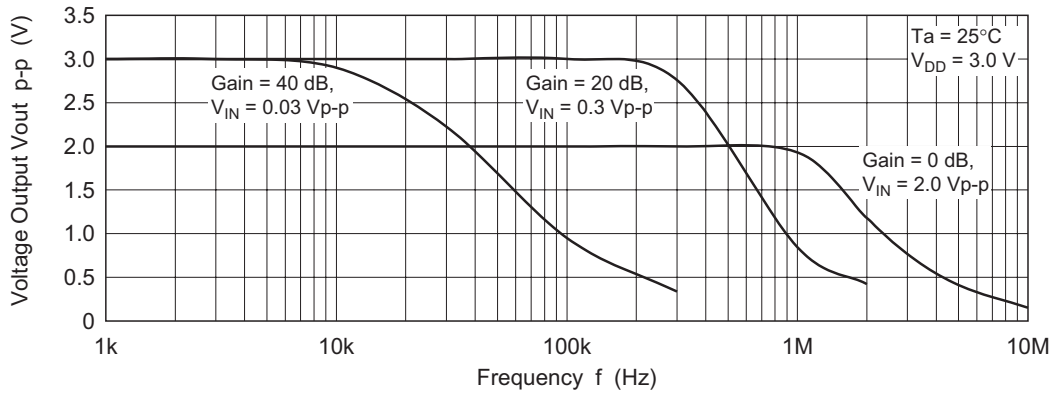
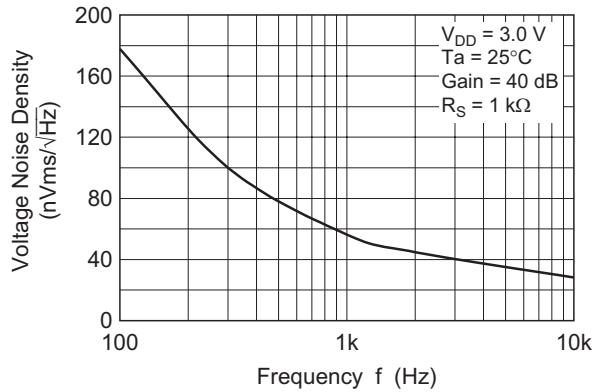
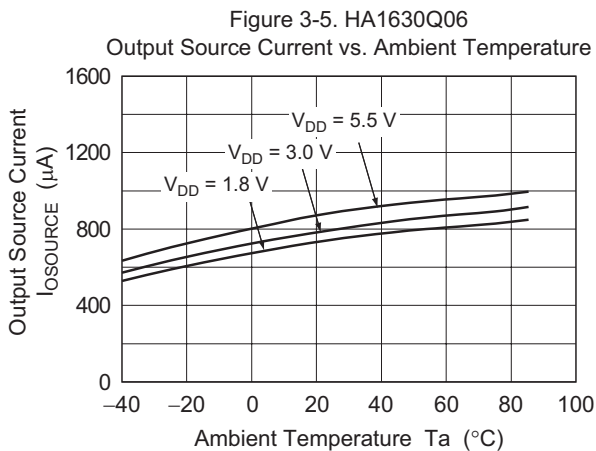
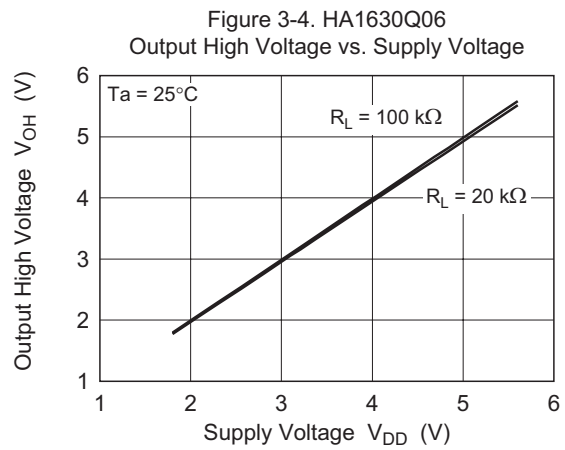
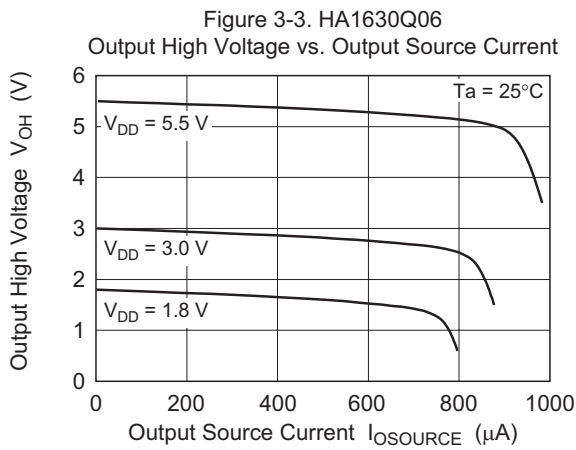
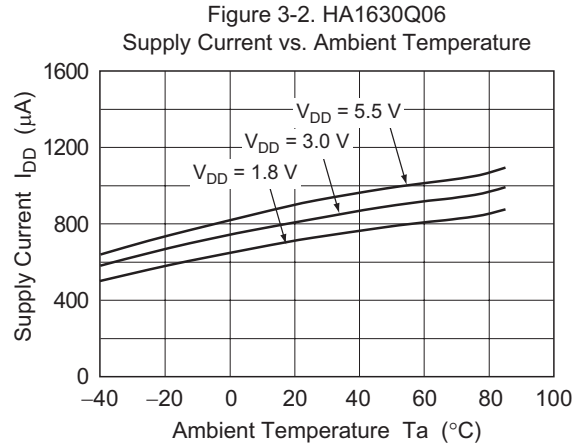
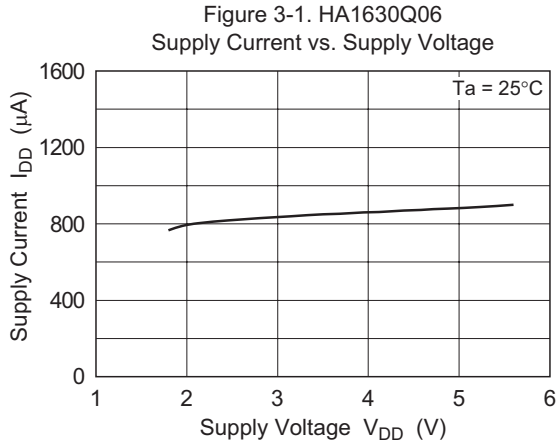


Figure 2-24. HA1630Q05
Voltage Noise Density vs. Frequency



Main Characteristics (HA1630Q06)



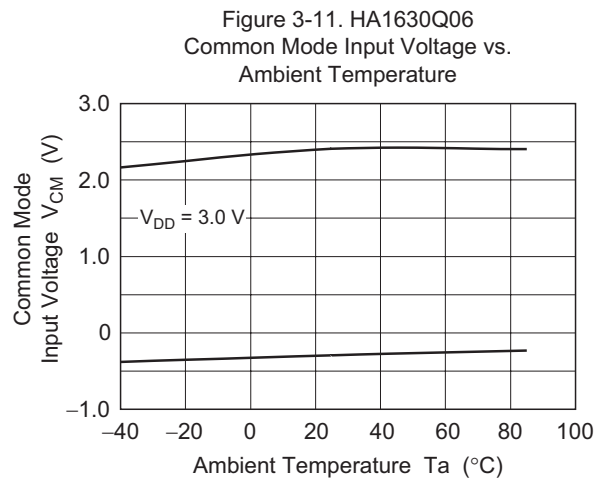
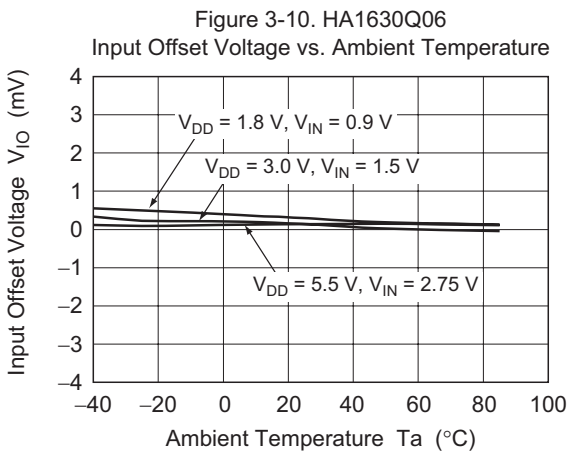
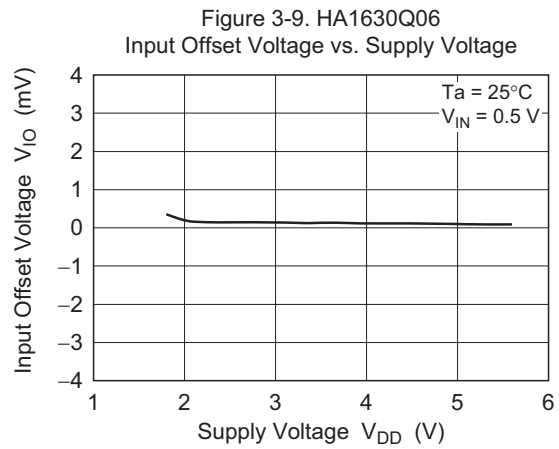
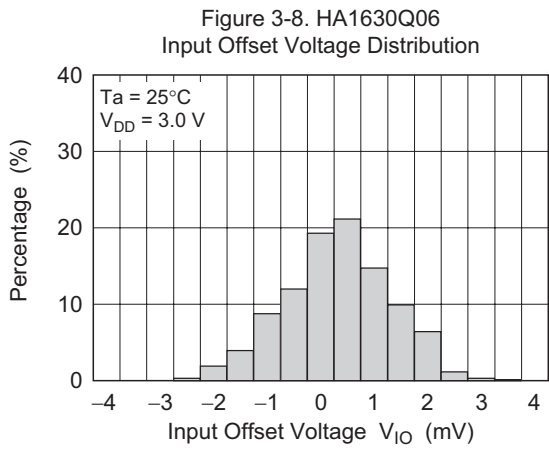
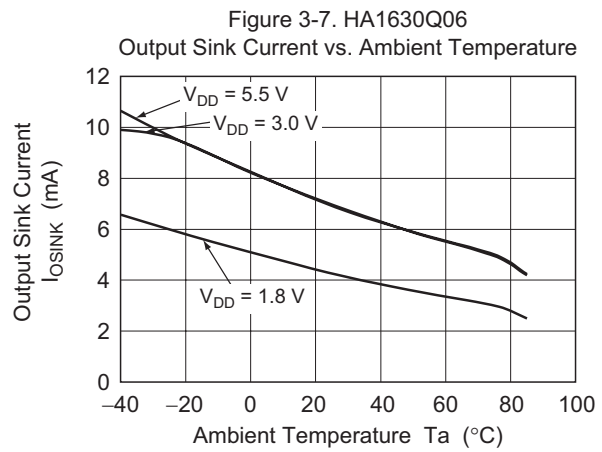
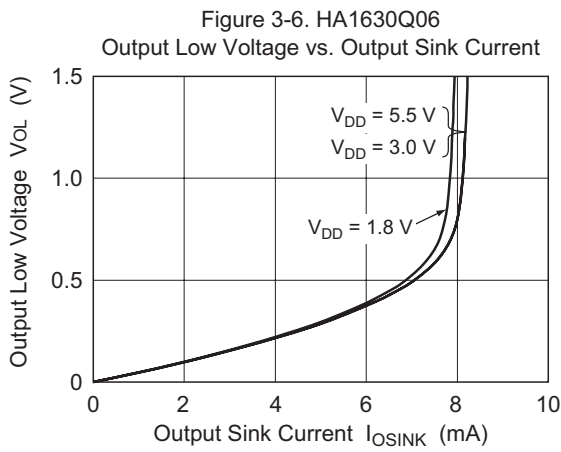


Figure 3-12. HA1630Q06
Power Supply Rejection Ratio vs. Frequency

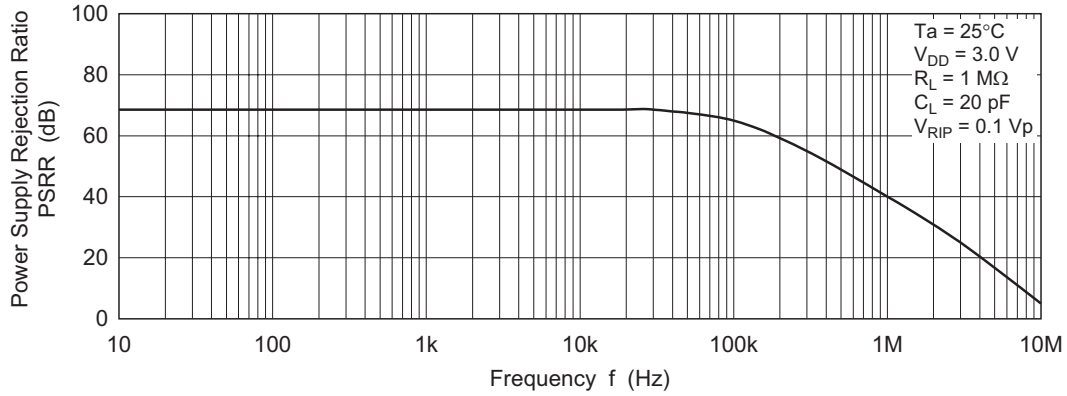


Figure 3-13. HA1630Q06
Common Mode Rejection Ratio vs. Frequency

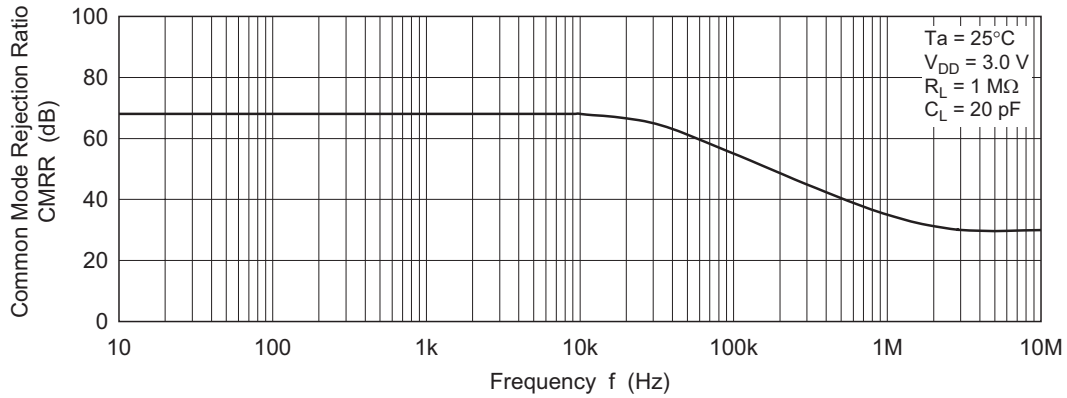


Figure 3-14. HA1630Q06
Open Loop Voltage Gain and Phase Angle vs. Frequency

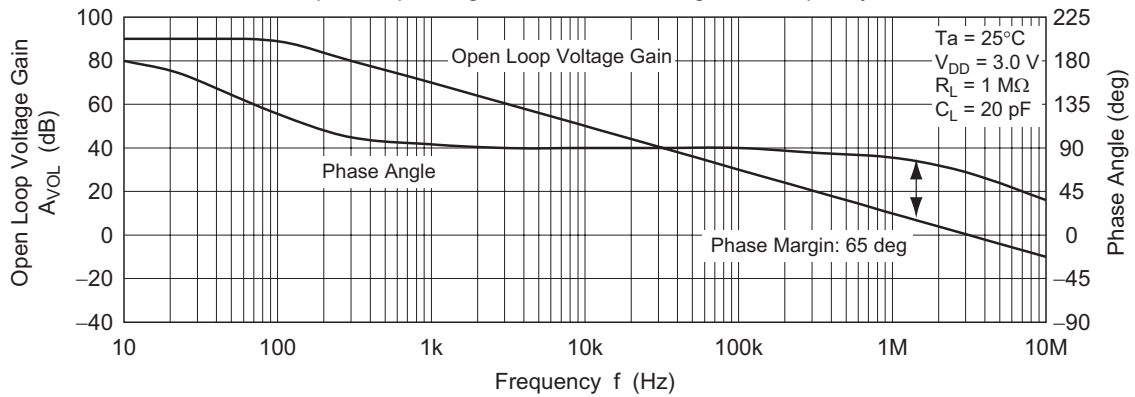


Figure 3-15. HA1630Q06
Input Bias Current vs. Ambient Temperature

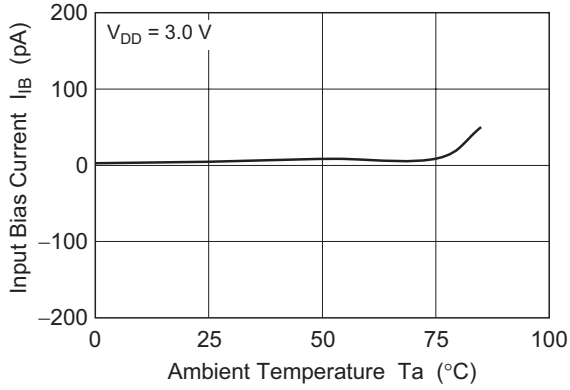


Figure 3-16. HA1630Q06
Input Bias Current vs. Input Voltage

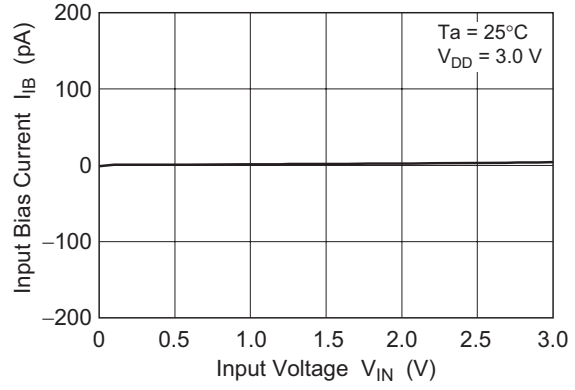


Figure 3-17. HA1630Q06
Slew Rate (rising) vs. Ambient Temperature

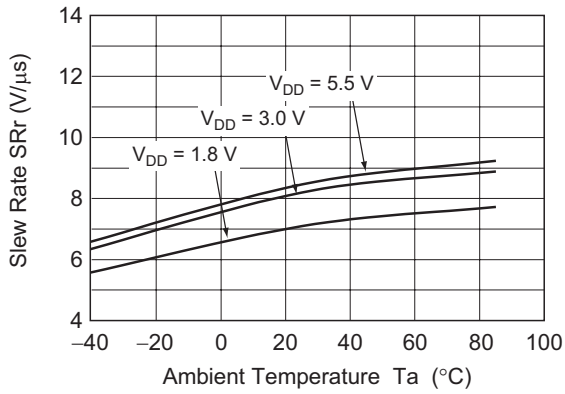


Figure 3-18. HA1630Q06
Slew Rate (falling) vs. Ambient Temperature

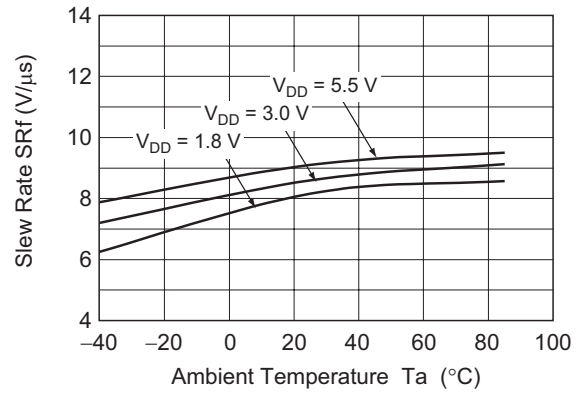


Figure 3-19. HA1630Q06
Large Signal Transient Response

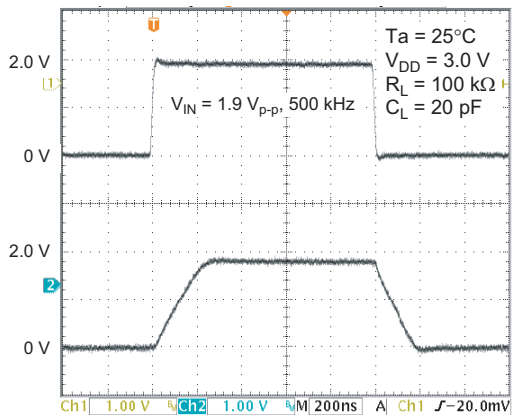


Figure 3-20. HA1630Q06
Small Signal Transient Response

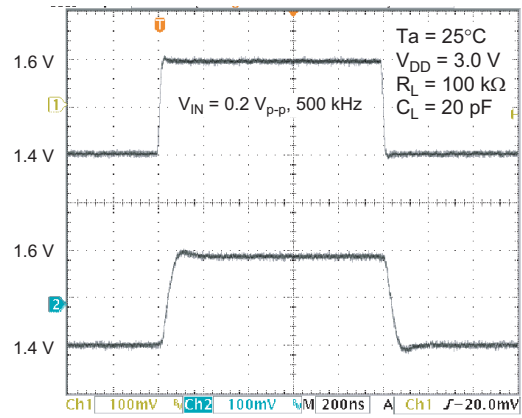


Figure 3-21. HA1630Q06
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

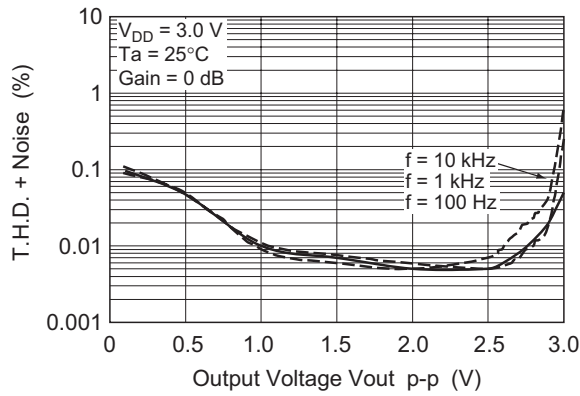


Figure 3-22. HA1630Q06
Total Harmonic Distortion + Noise vs.
Output Voltage p-p

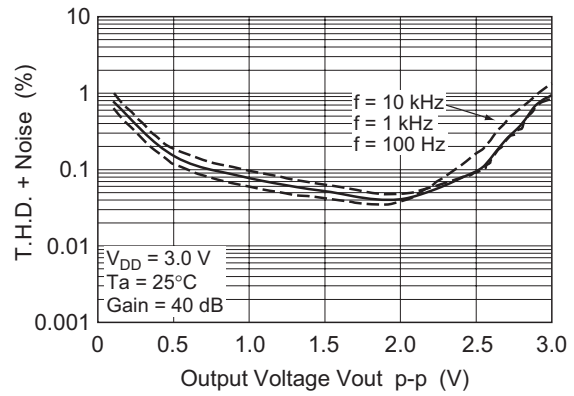


Figure 3-23. HA1630Q06
Voltage Output p-p vs. Frequency

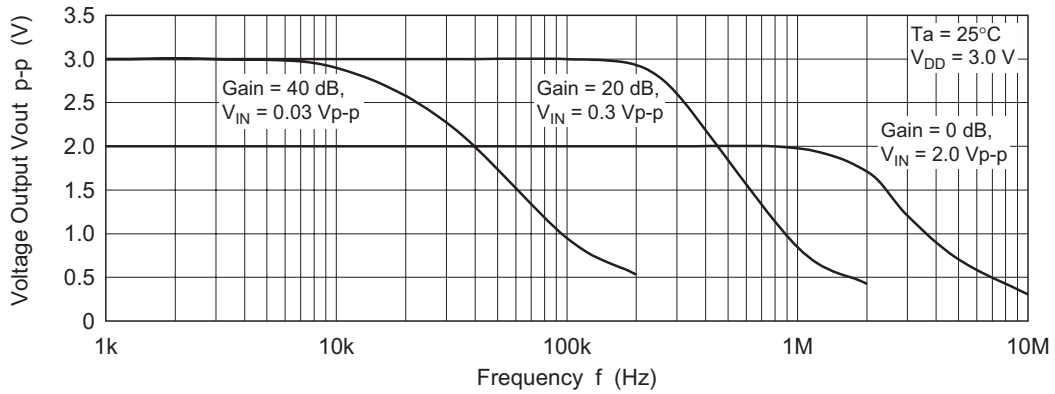
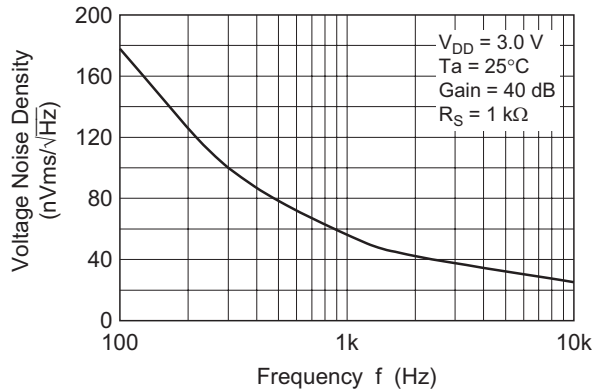
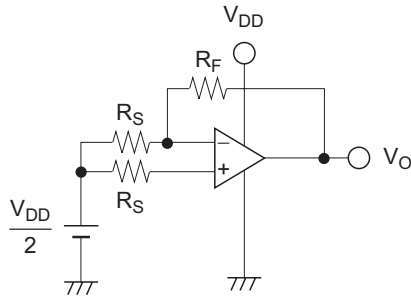


Figure 3-24. HA1630Q06
Voltage Noise Density vs. Frequency



Test Circuits

1. Power Supply Rejection Ratio, PSRR & Voltage Offset, V_{IO}



V_{IO}

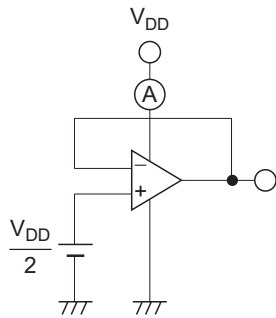
$$V_{IO} = \left(V_O - \frac{V_{DD}}{2} \right) \times \frac{R_S}{R_S + R_F}$$

PSRR

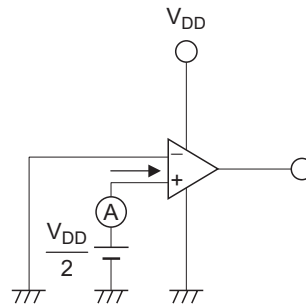
$$PSRR = -20 \log \left(\left| \frac{V_{O1} - V_{O2}}{V_{DD1} - V_{DD2}} \right| \times \frac{R_S}{R_S + R_F} \right)$$

Measure V_O corresponding to $V_{DD1} = 2.95 \text{ V}$ and $V_{DD2} = 3.05 \text{ V}$

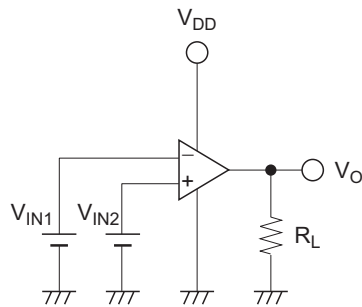
2. Supply Current, I_{DD}



3. Input Bias Current, I_{IB}



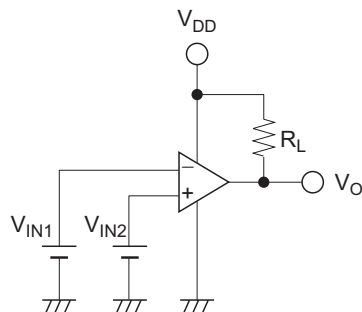
4. Output High Voltage, V_{OH}



V_{OH}

$$\begin{aligned} R_L &= 1 \text{ M}\Omega \\ V_{IN1} &= V_{DD} / 2 - 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 + 0.05 \text{ V} \end{aligned}$$

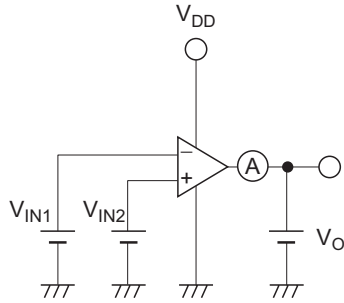
5. Output Low Voltage, V_{OL}



V_{OL}

$$\begin{aligned} R_L &= 1 \text{ M}\Omega \\ V_{IN1} &= V_{DD} / 2 + 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 - 0.05 \text{ V} \end{aligned}$$

6. Output Source Current, $I_{OSOURCE}$ & Output Sink Current, I_{OSINK}



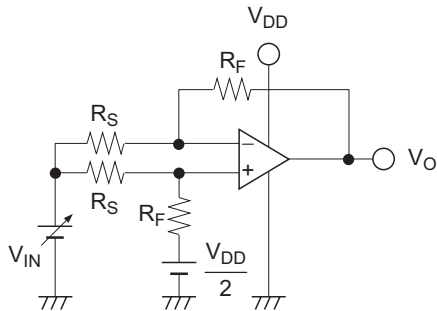
$I_{OSOURCE}$

$$\begin{aligned} V_O &= V_{DD} - 0.5 \text{ V} \\ V_{IN1} &= V_{DD} / 2 - 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 + 0.05 \text{ V} \end{aligned}$$

I_{OSINK}

$$\begin{aligned} V_O &= +0.5 \text{ V} \\ V_{IN1} &= V_{DD} / 2 + 0.05 \text{ V} \\ V_{IN2} &= V_{DD} / 2 - 0.05 \text{ V} \end{aligned}$$

7. Common Mode Input Voltage, V_{CM} & Common Mode Rejection Ratio, CMRR

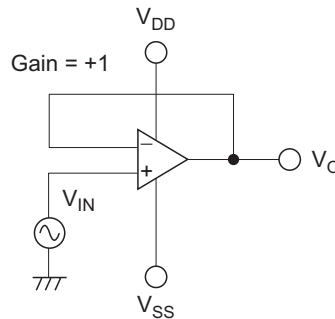
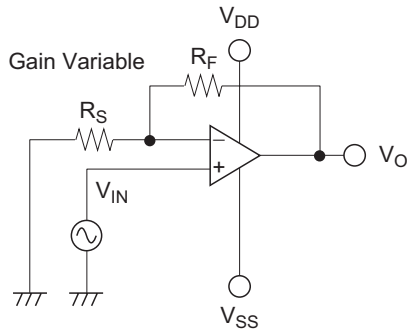


CMRR

$$CMRR = -20 \log \left(\left| \frac{V_{O1} - V_{O2}}{V_{IN1} - V_{IN2}} \right| \times \frac{R_S}{R_S + R_F} \right)$$

Measure V_O corresponding to $V_{IN1} = 0 \text{ V}$ and $V_{IN2} = 2.1 \text{ V}$

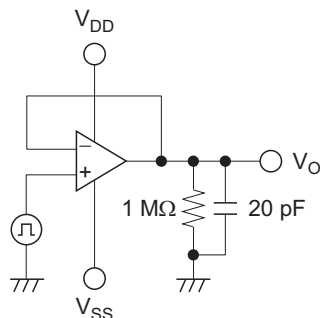
8. Total Harmonic Distortion, THD



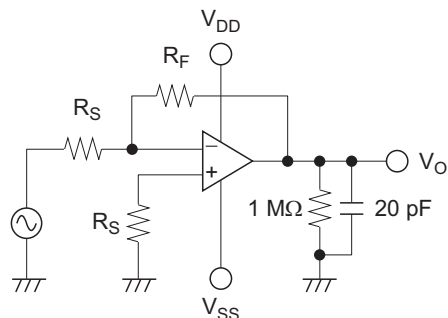
THD

Gain Variable
 $1 + R_F / R_S = 100$
 freq = 100 Hz, 1 kHz, 10 kHz

9. Slew Rate, SR

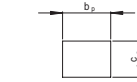
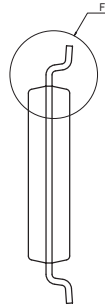
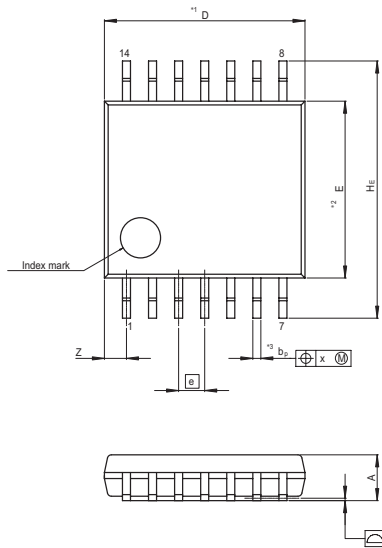


10. Gain, A_V & Phase, GBW

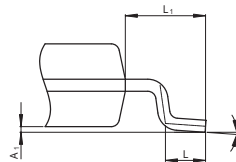


Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-TSSOP14-4.4x5-0.65	PTSP0014JA-B	TTP-14DV	0.05g



Terminal cross section
(Ni/Pd/Au plating)



Detail F

NOTE)
1. DIMENSIONS**1 (Nom)**AND**2*
DO NOT INCLUDE MOLD FLASH.
2. DIMENSION**3*DOES NOT
INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	5.00	5.30
E	—	4.40	—
A ₂	—	—	—
A ₁	0.03	0.07	0.10
A	—	—	1.10
b_p	0.15	0.20	0.25
b_1	—	—	—
c	0.10	0.15	0.20
c ₁	—	—	—
θ	0°	—	8°
H _E	6.20	6.40	6.60
ⓐ	—	0.65	—
x	—	—	0.13
y	—	—	0.10
Z	—	—	0.83
L	0.4	0.5	0.6
L ₁	—	1.0	—

Taping & Reel Specification

[Taping]

Package Code	W	P	A ₀	B ₀	K ₀	E	F	D ₁	Maximum Storage No.
TSSOP-14	12	8	6.5	5.1	1.5	—	5.5	1.6	2,000 pcs/reel

Unit: mm

[Reel]

Package	Tape width	W1	W2
TSSOP-14	12	17.4	13.4

[Ordering Information]

Ordering Unit
2,000 pcs

Mark Indication

(1) to (4)	Week code	
(5),(8) to (10)	Space	
(6), (7) (11), (12)	Product Name	0Q04 HA1630Q04
		0Q05 HA1630Q05
		0Q06 HA1630Q06

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